



# PRODUCT SPECIFICATION

**Model No : CST-532A9/533A9**

## Descriptions:

- 0.56 Inch Triad Digit Display
- CST-532: Common Anode
- CST-533: Common Cathode
- Emitting Color: Super Bright Amber



CUSTOMER APPROVED SIGNATURES	APPROVED BY	CHECKED BY	PREPARED BY

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<b>Spec. No.</b>	PS-ND-08090110
<b>Rev.</b>	A

**Model No : CST-532/533A9**

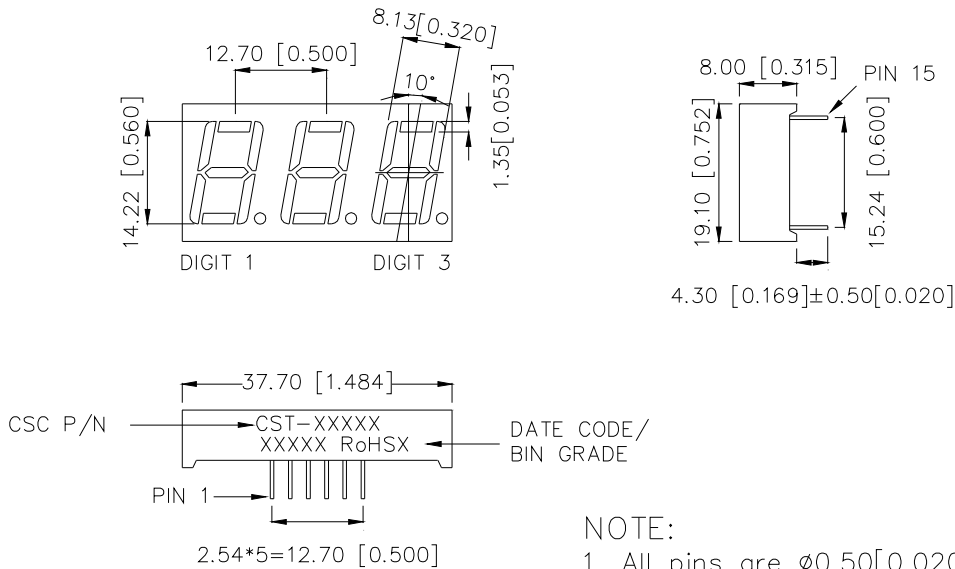
**Features -**

1. 0.56 inch (14.2mm) digit height.
2. Case mold type.
3. RoHS compliant.
4. Low power consumption.
5. Easy mounting on P.C. board or socket.

**Device Selection Guide -**

Part No.	Chip		Description
	Material	Emitted Color	
<b>CST-532A9</b>	<b>AlGaInP</b>	<b>Super Bright Amber</b>	<b>Common Anode</b>
<b>CST-533A9</b>	<b>AlGaInP</b>	<b>Super Bright Amber</b>	<b>Common Cathode</b>

**Package Dimensions -**



**NOTE:**

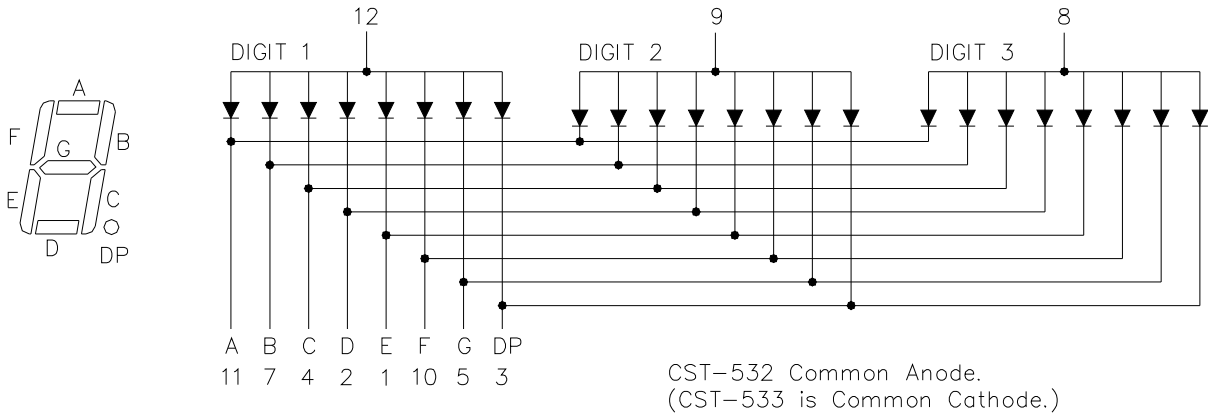
1. All pins are  $\varnothing 0.50 [0.020]$ .
2. Dimension in millimeters [inch], tolerance is  $\pm 0.25 [0.010]$  unless otherwise noted.



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**Internal Circuit Diagrams -**



**Absolute Maximum Rating -**

(Ta=25°C)

Parameter	Symbol	Rating	Unit
Power Dissipation Per Dice	PAD	70	mW
Continuous Forward Current Per Dice	IAF	25	mA
Peak Current Per Dice(duty cycle 1/10, 1kHz)	IPF	90	mA
Derating Linear From 25°C Per Dice	-	0.33	mA/°C
Reverse Voltage Per Dice	VR	5	V
Operating Temp.	Topr	-35 ~ +85	°C
Storage Temp.	Tstg	-35 ~ +85	°C
Solder temperature 1/16 inch below seating plane for 3 seconds at 260°C			



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■ **Electro-optical Characteristics -**

(Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Forward Voltage Per Segment	V <sub>F</sub>	-	2.0	2.8	V	I <sub>F</sub> =20mA
Luminous Intensity Per Segment	I <sub>v</sub>	-	25	-	mcd	I <sub>F</sub> =10mA
Peak Emission Wavelength	λ <sub>p</sub>	-	612	-	nm	I <sub>F</sub> =20mA
Dominant Wavelength	λ <sub>d</sub>	-	606	-	nm	I <sub>F</sub> =20mA
Spectrum Radiation Bandwidth	Δ λ	-	20	-	nm	I <sub>F</sub> =20mA
Reverse Current	I <sub>R</sub>	-	-	100	μA	V <sub>R</sub> =5V
Luminous Intensity Matching Ratio	I <sub>V-m</sub>	-	-	2:1	-	I <sub>F</sub> =10mA



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**Typical Electrical / Optical Characteristics Curves -**

**(Ta = 25°C Unless Otherwise Noted)**

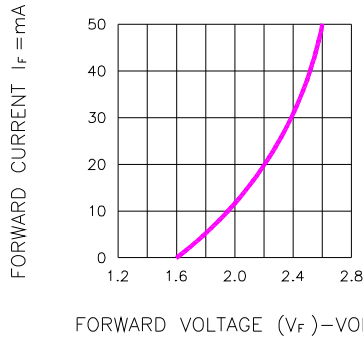


Fig.1 FORWARD CURRENT VS. FORWARD VOLTAGE

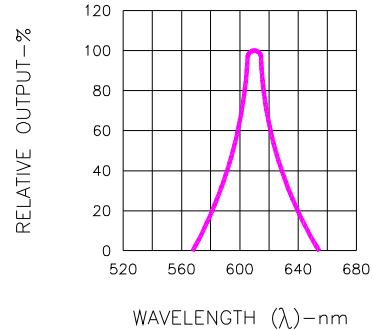


Fig.2 SPECTRAL RESPONSE

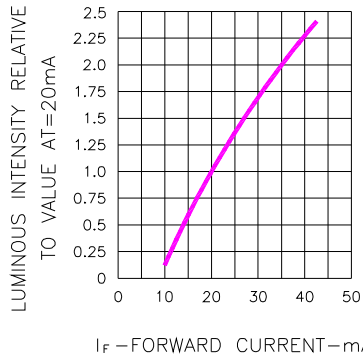


Fig.3 RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT

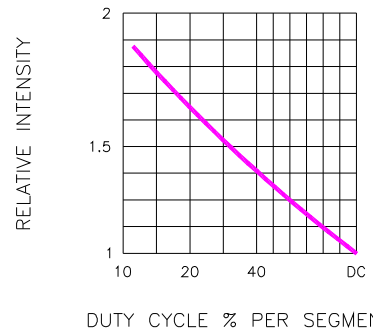


Fig.5 LUMINOUS INTENSITY VS. DUTY CYCLE

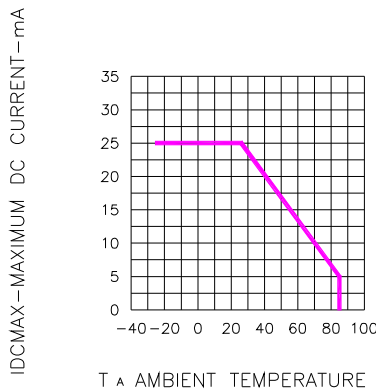


Fig.4 MAXIMUM ALLOWABLE DC CURRENT PER SEGMENT VS. A FUNCTION OF AMBIENT TEMPERATURE

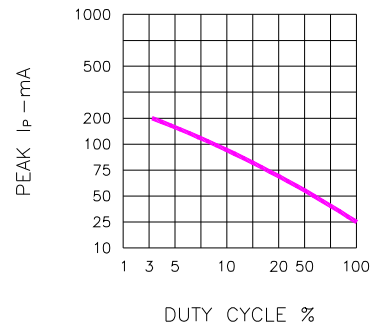


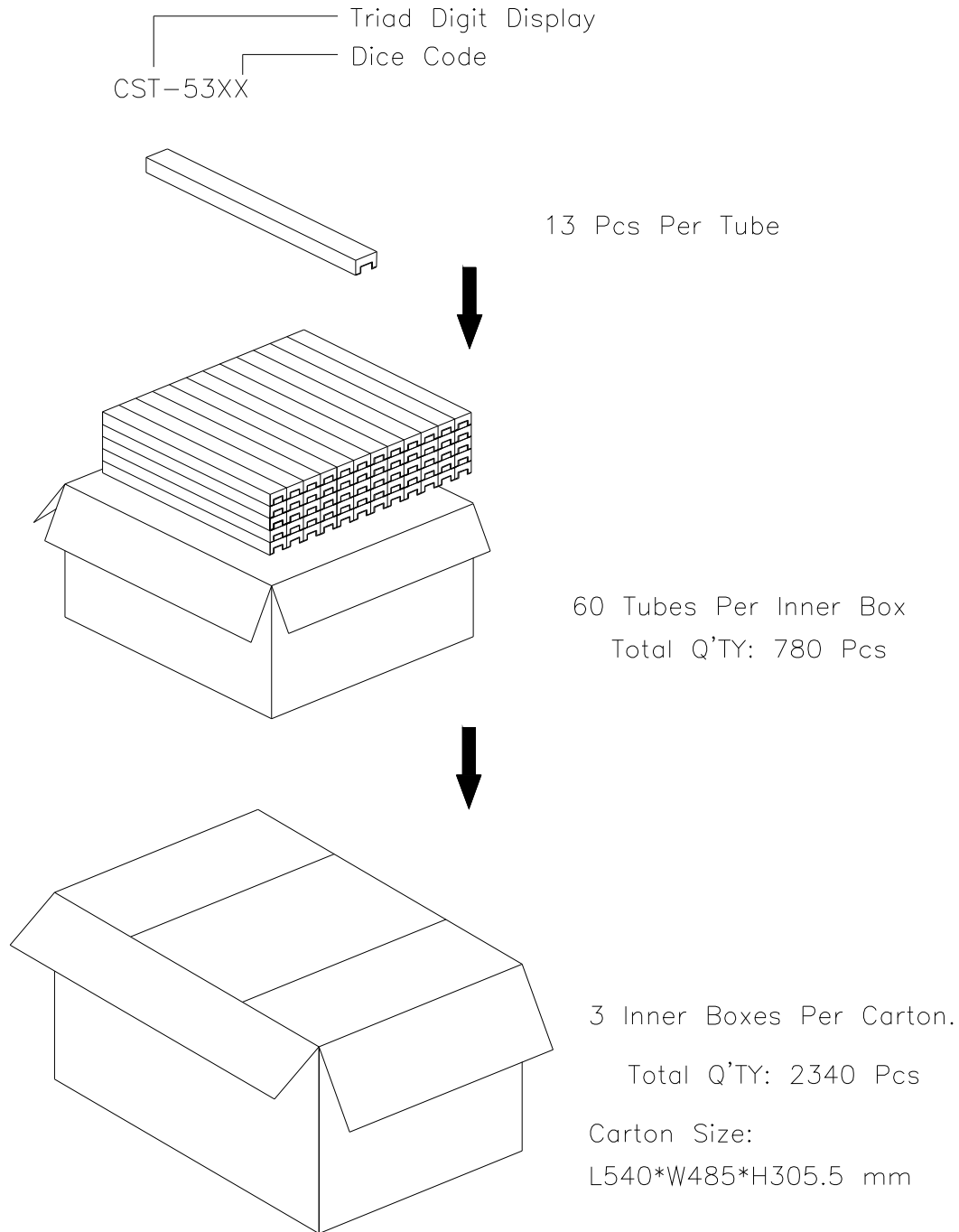
Fig.6 MAX PEAK CURRENT VS. DUTY CYCLE % (REFRESH RATE f=1 KHz)



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■ Package Dimensions



Note: The specifications are subject to change without notice. Please contact us for updated information.